

SPICE Device Model SUM45N25-58 Vishay Siliconix

N-Channel 250-V (D-S) 175°C MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

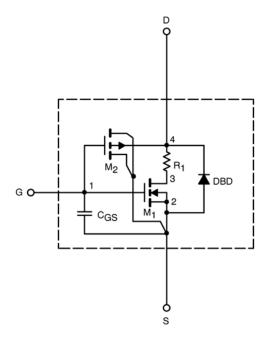
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125°C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			-		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.9		V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	112		А
Drain-Source On-State Resistance ^a	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	0.045	0.047	Ω
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}, T_J = 125^{\circ}\text{C}$	0.081		
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}, T_J = 175^{\circ}\text{C}$	0.100		
		V _{GS} = 6 V, I _D = 15 A	0.046	0.049	
Forward Voltage ^a	V _{SD}	$I_F = 45 \text{ A}, V_{GS} = 0 \text{ V}$	0.91	1	V
Dynamic ^b	-		·		
Input Capacitance	C _{iss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	4977	5000	pF
Output Capacitance	C _{oss}		326	300	
Reverse Transfer Capacitance	C _{rss}		229	170	
Total Gate Charge ^c	Q_g	V _{DS} = 125 V, V _{GS} = 10 V, I _D = 45 A	93	95	nC
Gate-Source Charge ^c	Q_gs		28	28	
Gate-Drain Charge ^c	Q_{gd}		34	34	
Turn-On Delay Time ^c	$t_{d(on)}$	$V_{DD} = 100 \text{ V}, R_L = 2.78 \Omega$ $I_D \cong 45 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 2.5 \Omega$	35	22	ns
Rise Time ^c	t _r		35	220	
Turn-Off Delay Time ^c	$t_{d(off)}$		56	40	
Fall Time ^c	t _f		44	145	

Notes

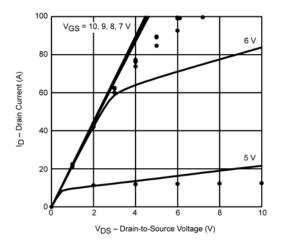
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

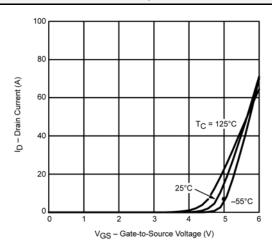


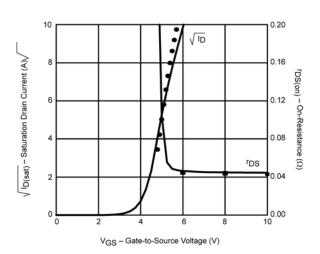
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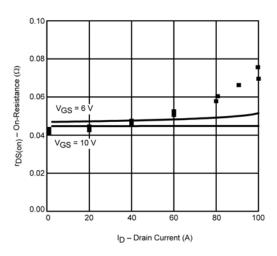
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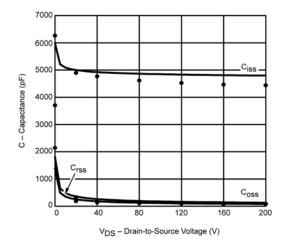
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

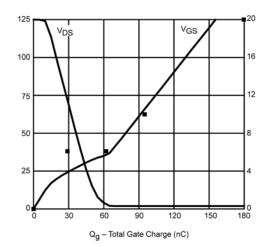












Note: Dots and squares represent measured data.



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